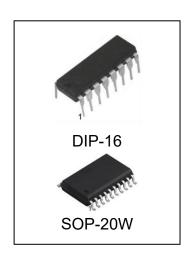


PUSH-PULL FOUR CHANNEL DRIVER WITH DIODES

FEATURES

- 600mA Output Current Capability Per Channel
- 1.0 A Peak Output Current(Non Repeti-Tive) Per Channel
- Enable Facility Overtemperature Protection
- Logical "0" Input Voltage Up To 1.5 V (High Noise Immunity)
- Internal Clamp Diodes



ORDERING INFORMATION

DEVICE	Package Type	MARKING	Packing	Packing Qty
L293DN	DIP-16	L293D	TUBE	1000pcs/box
L293DDM/TR	SOP-20W	L293D	REEL	2000pcs/reel



DESCRIPTION

The Device is a monolithic integrated high volt- age, high current four channel driver designed to accept standard DTL or TTL logic levels and drive inductive loads (such as relays solenoides, DC and stepping motors) and switching power tran- sistors.

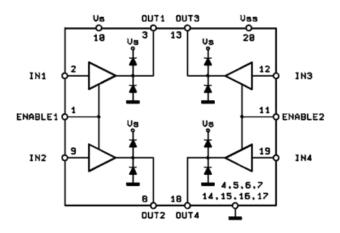
To simplify use as two bridges each pair of chan- nels is equipped with an enable input. A separate supply input is provided for the logic, allowing op- eration at a lower voltage and internal clamp di- odes are included.

This device is suitable for use in switching appli- cations at frequencies up to 5 kHz.

The L293D is assembled in a 16 lead plastic packaage which has 4 center pins connected to- gether and used for heatsinking

The L293DD is assembled in a 20 lead surface mount which has 8 center pins connected to- gether and used for heatsinking.

BLOCK DIAGRAM



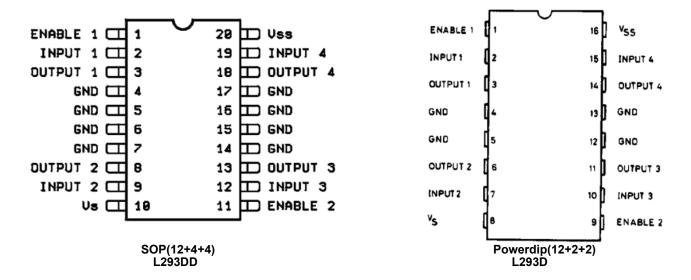


ABSOLUTE MAXIMUM RATINGS

Symbol	Parameter	Value	Unit
Vs	Supply Voltage	36	V
Vss	Logic Supply Voltage	36	V
Vi	Input Voltage	7	V
V _{en}	Enable Voltage	7	V
Io	Peak Output Current (100µs non repetitive)	1.0	Α
P _{tot}	Total Power Dissipation at T_{pins} = 90 $^{\circ}$ C	4	W
TL	Lead Temperature (Soldering, 10 seconds)	260	$^{\circ}\mathbb{C}$
T _{stg} , T _j	Storage and Junction Temperature	-40 ~ 150	$^{\circ}\mathbb{C}$
T _A	Operating Temperature Range	-20 ~ 85	$^{\circ}\!\mathbb{C}$

Note: Absolute Maximum Ratings indicate limits beyond which damage to the device may occur. Operating Ratings indicate conditions for which the device is intended to be functional, but specific performance is not ensured.

PIN CONNECTIONS (Top view)



THERMAL DATA

Symbol	Decription		DIP	SOP	Unit
R _{th j-pins}	Thermal Resistance Junction-pins	max.	_	14	°C/W
R _{th j-amb}	Thermal Resistance junction-ambient	max.	80	50 (*)	°C/W
R _{th j-case}	Thermal Resistance Junction-case	max.	14	_	

^(*) With 6sq. cm on board heatsink.



ELECTRICAL CHARACTERISTICS

(for each channel, VS=24V, VSS=5V,Tamb=25 °C, unlessotherwise specified)

Symbol	Parameter	Test Conditions	Min.	Тур.	Max.	Unit
Vs	Supply Voltage (pin 10)		V _{SS}		36	V
V _{SS}	Logic Supply Voltage (pin 20)		4.5		36	V
Is	Total Quiescent Supply Current	$V_i = L$; $I_0 = 0$; $V_{en} = H$		2	6	mA
	(pin 10)	$V_i = H \; ; \; I_O = 0 \; ; \; V_{en} = H$		16	24	mA
		V _{en} = L			4	mA
I _{SS}	Total Quiescent Logic Supply	$V_i = L \; ; \; I_O = 0 \; ; \; V_{en} = H$		44	60	mA
	Current (pin 20)	$V_i = H \; ; \; I_O = 0 \; ; \; V_{en} = H$		16	22	mA
		V _{en} = L		16	24	mA
VIL	Input Low Voltage (pin 2, 9, 12, 19)		-0.3		1.5	V
V _{IH}	Input High Voltage (pin 2, 9,	V _{SS} 7 V	2.3		V _{SS}	V
	12, 19)	V _{SS} > 7 V	2.3		7	V
I _{IL}	Low Voltage Input Current (pin2, 9, 12, 19)	V _{IL} = 1.5 V			- 10	μА
Іін	High Voltage Input Current (pin2, 9, 12, 19)	2.3 V V _{IH} V _{SS} - 0.6 V		30	100	μA
V _{en L}	Enable Low Voltage(pin 1, 11)		- 0.3		1.5	V
V _{en H}	Enable High Voltage	V _{SS} 7 V	2.3		Vss	V
	(pin 1, 11)	V _{SS} > 7 V	2.3		7	V
I _{en L}	Low Voltage Enable Current(pin 1, 11)	V _{en L} = 1.5 V		- 30	- 100	μA
l _{en H}	High Voltage Enable Current(pin 1, 11)	2.3 V V _{en H} V _{SS} – 0.6 V			±10	μA
V _{CE(sat)H}	Source Output Saturation Voltage (pins 3, 8, 13, 18)	I _O = - 0.6 A		1.4	1.8	V
V _{CE(sat)L}	Sink Output Saturation Voltage(pins 3, 8, 13, 18)	I _O = + 0.6 A		1.2	1.8	V
V _F	Clamp Diode Forward Voltage	I _O = 600nA		1.3		V
t _r	Rise Time (*)	0.1 to 0.9 V _O		250		ns
t _f	Fall Time (*)	0.9 to 0.1 V _O		250		ns
t _{on}	Turn-on Delay (*)	0.5 V _i to 0.5 V _O		750		ns
t _{off}	Turn-off Delay (*)	0.5 V _i to 0.5 V ₀		200		ns

^(*) See fig. 1.



TRUTH TABLE (one channel)

Input	Enable (*)	Output
Н	Н	Н
L	Н	L
Н	L	Z
L	L	Z

Z = High output impedance

Figure 1: Switching Times

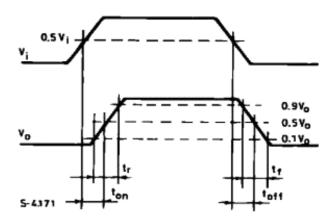
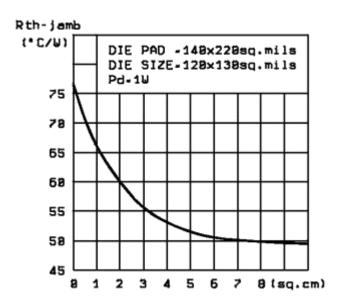
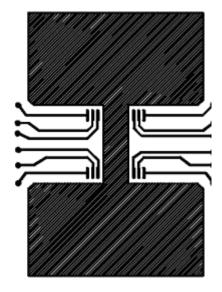


Figure 2: Junction to ambient thermal resistance vs. area on board heatsink (SOP 12+4+4 package)





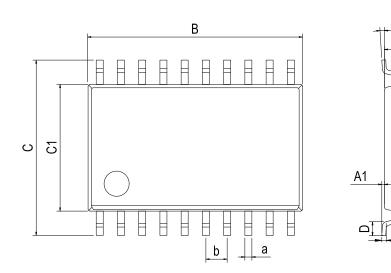
^(*) Relative to the considered channe

0.25



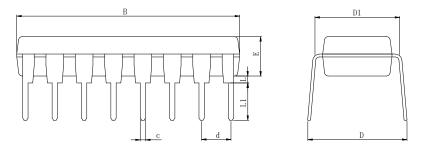
PHYSICAL DIMENSIONS

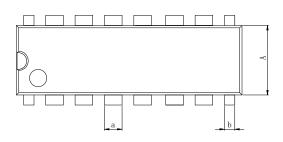
SOP-20W



Dimensions In Millimeters(SOP-20W)									
Symbol:	Α	A1	В	С	C1	D	Q	а	b
Min:	2.10	0.05	12.50	10.21	7.40	0.45	0°	0.35	1.27 BSC
Max:	2.50	0.25	13.00	10.61	7.60	1.25	8°	0.45	1.27 650

DIP-16





Dimensions In Millimeters(DIP-16)											
Symbol:	Α	В	D	D1	Е	L	L1	а	b	С	d
Min:	6.10	18.94	8.10	7.42	3.10	0.50	3.00	1.50	0.85	0.40	2.54.000
Max:	6.68	19.56	10.9	7.82	3.55	0.70	3.60	1.55	0.90	0.50	2.54 BSC



Revision History

DATE	REVISION	PAGE
2018-8-3	New	1-8
2023-9-13	Update encapsulation type 、 Updated DIP-16 dimension 、 Add annotation for Maximum Ratings.	1、6
2024-10-31	Updated max Peak Output Current Update packages model SOP-20W Update Lead Temperature	1、3



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